L Number	Hits	Search Text	DB	Time stamp
-	100	("5578862" "6013950" "4338571" "4898837" "5221857" "5583058" "5587612" "5633190" "5858850" "5252502" "4475955" "4495222" "4499557" "4560422" "4600658" "4971926" "5320932" "5329155" "5502327" "5668755" "5670819" "5751050" "5821587" "5970338" "6031266" "6124615" "6229190" "6242792" "6445055" "4259564" "4326213" "4609935" "4782202" "4947020" "5276346" "5356826" "5391906" "5436483" "5436484" "5534723" "5610089" "5618749" "5963279" "4265117" "4620212" "4626881" "4755480" "4786612" "4847783" "4975386").pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 16:55
-	257	((resistor or gate) with sti) same active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 15:15
-	189	((resistor or gate) with sti) with active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 17:00
-	37	(((resistor or gate) with sti) with active) and 257/$3.ccls. and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 17:56
-	192	resistor with (dielectric or insulator) with active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 18:46

–	28	(resistor with (dielectric or insulator) with active) and 257/$3.ccls. and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 18:47
–	12	("3574932" | "4179310" | "4468414" | "4594265" | "4704188" | "4708747" | "4839711" | "5179434" | "5367284" | "5414404" | "5525831" | "6316325" | "2001/0017397").PN.	USPAT	2003/03/27 18:38
–	52	resistive with (dielectric or insulator) with active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 18:46
–	8	(resistive with (dielectric or insulator) with active) and 257/$3.ccls. and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/27 18:47
–	2178	resistor with (over or under) with (dielectric or insulat$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:19
–	86	(resistor with (over or under) with (dielectric or insulat$3)) same active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 14:15
–	74	((resistor with (over or under) with (dielectric or insulat$3)) same active) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:24
–	204	(resistor with (over or under) with (dielectric or insulat$3)) and (width with resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 16:53
–	12	((resistor with (over or under) with (dielectric or insulat$3)) same active) and (width with resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 16:59
–	9	((resistor with (over or under) with (dielectric or insulat$3)) same active) and dummy	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 16:59
–	3	((resistor with (over or under) with (dielectric or insulat$3)) same active) and (distance with between with resistors)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:20
–	105	(resistor with (over or under) with (dielectric or insulat$3)) and (distance with between with resistors)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:46
–	94	((resistor with (over or under) with (dielectric or insulat$3)) and (distance with between with resistors)) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:24

-	3	(dummy adj gate) same resistor same active same (insulator or dielectric)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:51
-	4	(dummy adj gate) and (resistor same active same (insulator or dielectric))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:51
-	2	(resistor with over with sti) same active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:58
-	8	(resistor with sti) same active	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/03/31 17:58
-	0	jp-9022641-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 16:08
-	0	jp-90022641-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 16:09
-	1	jp-3227060-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 17:08
-	8314	transistor with common with source with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 17:09
-	711	transistor with common with source with drain with series	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:04
-	50	(transistor with common with source with drain with series) same insulat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 17:13
-	46	((transistor with common with source with drain with series) same insulat$3) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:32
-	12404	transistor with coupled with series	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:05
-	1289	transistor with coupled with series with source with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:11
-	2	(transistor with coupled with series with source with drain) and 257/401.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:12
-	7	(transistor with coupled with series) and 257/401.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:11
-	1233	257/401.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:32
-	79	257/401.ccls. and (shar$3 with source with drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:36
-	73	(257/401.ccls. and (shar$3 with source with drain)) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:12

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–	2	257/401.ccls. and ((shar$3 with source with drain) same trench)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:38
–	0	(transistor with coupled with series with source with drain) same sti	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:38
–	2	(transistor with coupled with series) same sti	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:39
–	1	(transistor with coupled with series) same (shallow adj trench)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:40
–	20	(shallow adj trench) same (source with drain with series)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:50
–	27	(shallow adj trench) same (source with drain with coupled)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:51
–	12	((shallow adj trench) same (source with drain with coupled)) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 18:51
–	10238	form$3 with resistor with insulat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:04
–	44	(transistor with coupled with series) and (form$3 with resistor with insulat$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:10
–	122765	(source or drain or active) with (shallow or sti or resistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:11
–	752	(form$3 with resistor with insulat$3) same ((source or drain or active) with (shallow or sti or resistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:11
–	1	((form$3 with resistor with insulat$3) same ((source or drain or active) with (shallow or sti or resistor))) and 257/401.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:11
–	259	((form$3 with resistor with insulat$3) same ((source or drain or active) with (shallow or sti or resistor))) and 257/$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:40
–	225	(((form$3 with resistor with insulat$3) same ((source or drain or active) with (shallow or sti or resistor))) and 257/$3.ccls.) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:58
–	15	form$3 with resistor with over with (shallow or sti)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:24
–	105	form$3 with resist$4 with over with (shallow or sti)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:24
–	31	(form$3 with resist$4 with over with (shallow or sti)) and 257/$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:58
–	2	transistor same coupled same series same shallow same trench	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:40

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-	14	(source or drain) same coupled same series same shallow same trench	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:39
-	71	transistor same coupled same shallow same trench	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:40
-	30	(transistor same coupled same shallow same trench) and 257/$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:57
-	13	("4426686" | "5117389" | "5329483" | "5477484" | "5703820" | "5745401" | "5787033" | "5866457" | "5930180" | "6084794" | "6136648" | "6236587" | "6363001" | "2002/0060347").PN.	USPAT	2003/11/17 19:43
-	13	("4426686" | "5117389" | "5329483" | "5477484" | "5703820" | "5745401" | "5787033" | "5866457" | "5930180" | "6084794" | "6136648" | "6236587" | "6363001" | "2002/0060347").PN.	USPAT	2003/11/17 19:51
-	193	dielectric and isolation and bit and word and rom and node and diffusion	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:18
-	73	(dielectric and isolation and bit and word and rom and node and diffusion) and 257/$3.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 19:58
-	59	((dielectric and isolation and bit and word and rom and node and diffusion) and 257/$3.ccls.) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:24
-	2	(word adj line) with over with (dielectric adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:09
-	13	(word adj line) with over with (shallow adj trench)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:09
-	9	((word adj line) with over with (shallow adj trench)) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:13
-	49	poplevine.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:13
-	0	(dielectric adj isolation) with resistor with node	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:18
-	10	(dielectric adj isolation) with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:20
-	7	(fox) with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:22
-	5	sti with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:23
-	37	trench with resistor with over	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:23

-	27	(trench with resistor with over) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:31
-	44	(shallow adj trench) with separated with active with regions	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:55
-	23	((shallow adj trench) with separated with active with regions) and @ad<20010305	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:31
-	9	("5429956" | "5434093" | "5538913" | "5677218" | "5686321" | "5698461" | "5712501" | "5712503" | "5766998").PN.	USPAT	2003/11/17 20:37
-	15	((shallow adj trench) with active with regions) same resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:47
-	478	isolation with separated with active with regions	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:55
-	7	isolation with separated with active with regions with resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:57
-	0	653108.apn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/11/17 20:57